

勝特力材料 886-3-5753170  
 胜特力电子(上海) 86-21-54151736  
 胜特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

ON

## Complementary Silicon Power Transistors

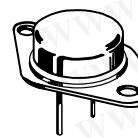
The 2N3773 and 2N6609 are PowerBase™ power transistors designed for high power audio, disk head positioners and other linear applications. These devices can also be used in power switching circuits such as relay or solenoid drivers, dc to dc converters or inverters.

- High Safe Operating Area (100% Tested) 150 W @ 100 V
- Completely Characterized for Linear Operation
- High DC Current Gain and Low Saturation Voltage  
 $h_{FE} = 15$  (Min) @ 8 A, 4 V  
 $V_{CE(sat)} = 1.4$  V (Max) @  $I_C = 8$  A,  $I_B = 0.8$  A
- For Low Distortion Complementary Designs

NPN  
**2N3773\***  
 PNP  
**2N6609**

\*ON Semiconductor Preferred Device

16 AMPERE  
 COMPLEMENTARY  
 POWER TRANSISTORS  
 140 VOLTS  
 150 WATTS



CASE 1-07  
 TO-204AA  
 (TO-3)

### \*MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector Emitter Voltage	$V_{CEO}$	140	Vdc
Collector-Emitter Voltage	$V_{CEX}$	160	Vdc
Collector-Base Voltage	$V_{CBO}$	160	Vdc
Emitter-Base Voltage	$V_{EBO}$	7	Vdc
Collector Current — Continuous — Peak (1)	$I_C$	16 30	Adc
Base Current — Continuous — Peak (1)	$I_B$	4 15	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	150 0.855	Watts $\text{W}/^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.17	°C/W

\*Indicates JEDEC Registered Data.

(1) Pulse Test: Pulse Width = 5 ms, Duty Cycle  $\leq 10\%$ .

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

# 2N3773 2N6609

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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## OFF CHARACTERISTICS (2)

*Collector-Emitter Breakdown Voltage ( $I_C = 0.2 \text{ Adc}, I_B = 0$ )	$V_{CEO(\text{sus})}$	140	—	Vdc
*Collector-Emitter Sustaining Voltage ( $I_C = 0.1 \text{ Adc}, V_{BE(\text{off})} = 1.5 \text{ Vdc}, R_{BE} = 100 \text{ Ohms}$ )	$V_{CEX(\text{sus})}$	160	—	Vdc
Collector-Emitter Sustaining Voltage ( $I_C = 0.2 \text{ Adc}, R_{BE} = 100 \text{ Ohms}$ )	$V_{CER(\text{sus})}$	150	—	Vdc
*Collector Cutoff Current ( $V_{CE} = 120 \text{ Vdc}, I_B = 0$ )	$I_{CEO}$	—	10	mAdc
*Collector Cutoff Current ( $V_{CE} = 140 \text{ Vdc}, V_{BE(\text{off})} = 1.5 \text{ Vdc}$ ) ( $V_{CE} = 140 \text{ Vdc}, V_{BE(\text{off})} = 1.5 \text{ Vdc}, T_C = 150^\circ\text{C}$ )	$I_{CEX}$	— —	2 10	mAdc
Collector Cutoff Current ( $V_{CB} = 140 \text{ Vdc}, I_E = 0$ )	$I_{CBO}$	—	2	mAdc
*Emitter Cutoff Current ( $V_{BE} = 7 \text{ Vdc}, I_C = 0$ )	$I_{EBO}$	—	5	mAdc

## ON CHARACTERISTICS (2)

DC Current Gain *( $I_C = 8 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$ ) ( $I_C = 16 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$ )	$h_{FE}$	15 5	60 —	—
Collector-Emitter Saturation Voltage *( $I_C = 8 \text{ Adc}, I_B = 800 \text{ mAdc}$ ) ( $I_C = 16 \text{ Adc}, I_B = 3.2 \text{ Adc}$ )	$V_{CE(\text{sat})}$	— —	1.4 4	Vdc
*Base-Emitter On Voltage ( $I_C = 8 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$ )	$V_{BE(\text{on})}$	—	2.2	Vdc

## DYNAMIC CHARACTERISTICS

Magnitude of Common-Emitter Small-Signal, Short-Circuit, Forward Current Transfer Ratio ( $I_C = 1 \text{ A}, f = 50 \text{ kHz}$ )	$ h_{fe} $	4	—	—
*Small-Signal Current Gain ( $I_C = 1 \text{ Adc}, V_{CE} = 4 \text{ Vdc}, f = 1 \text{ kHz}$ )	$h_{fe}$	40	—	—

## SECOND BREAKDOWN CHARACTERISTICS

Second Breakdown Collector Current with Base Forward Biased $t = 1 \text{ s}$ (non-repetitive), $V_{CE} = 100 \text{ V}$ , See Figure 12	$I_{S/b}$	1.5	—	Adc
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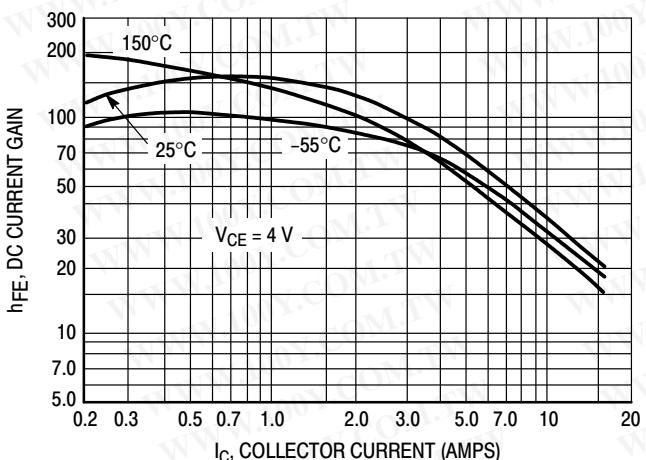
(2) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

\*Indicates JEDEC Registered Data.

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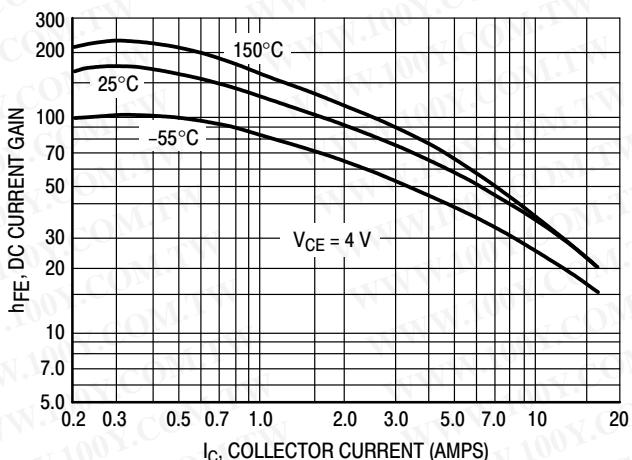
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**NPN**

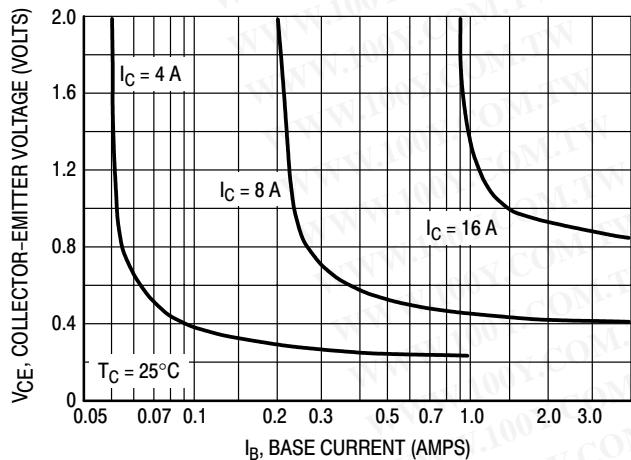


**Figure 6. DC Current Gain**

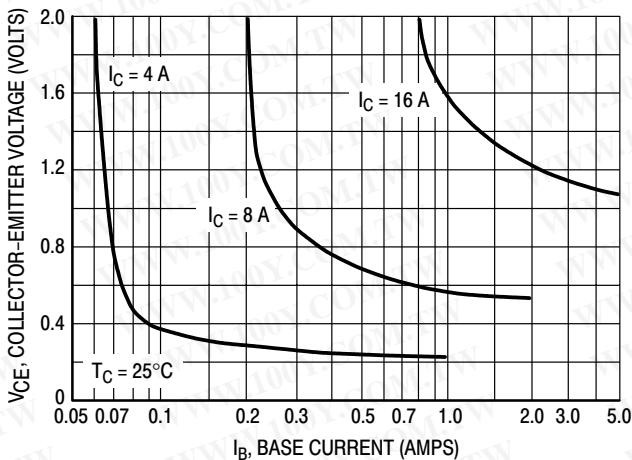
**PNP**



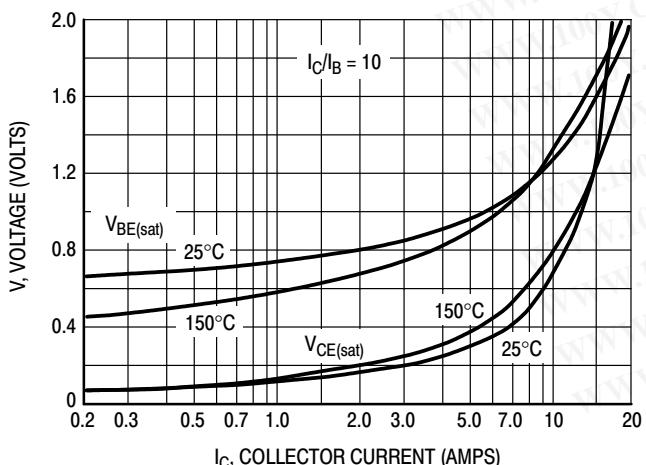
**Figure 7. DC Current Gain**



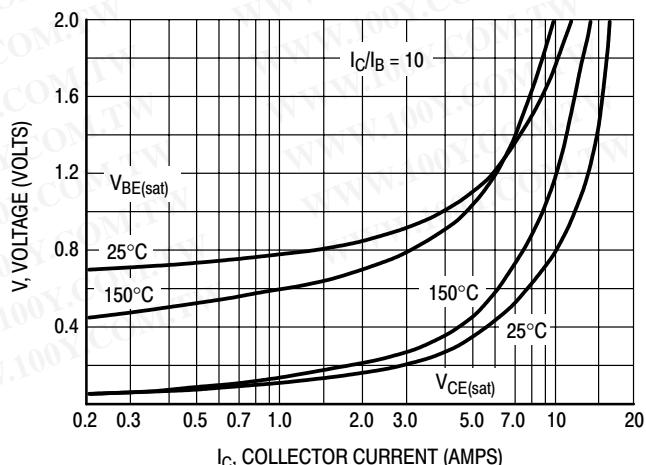
**Figure 8. Collector Saturation Region**



**Figure 9. Collector Saturation Region**



**Figure 10. "On" Voltage**



**Figure 11. "On" Voltage**

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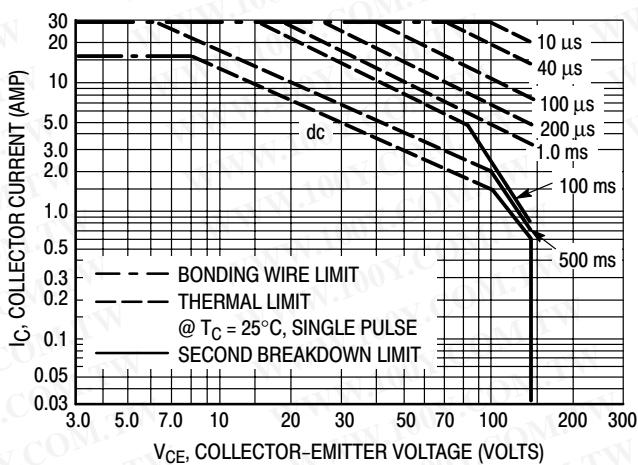


Figure 12. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C$  –  $V_{CE}$  limits of the transistor that must be observed for reliable operation: i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 7 is based on  $T_{J(pk)} = 200^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse

limits are valid for duty cycles to 10% provided  $T_{J(pk)} < 200^\circ\text{C}$ . At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

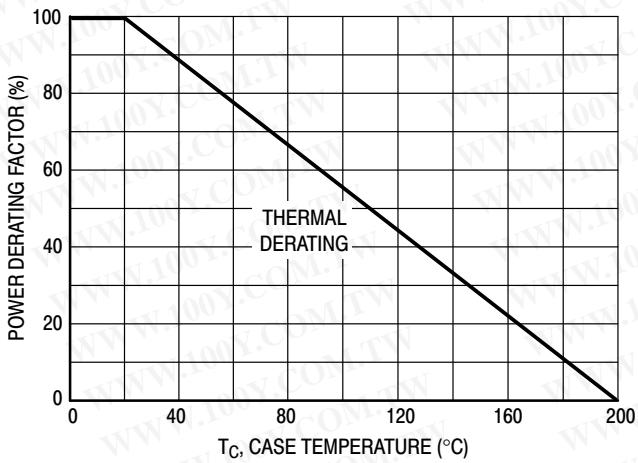


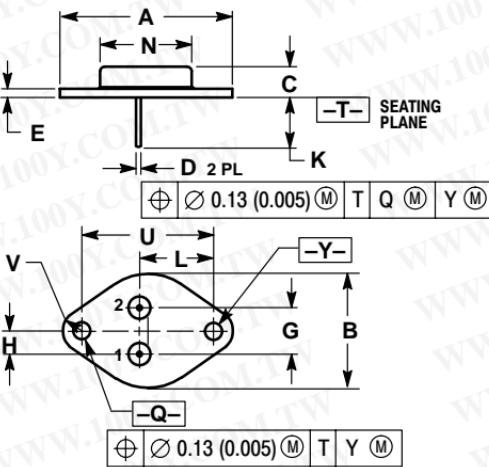
Figure 13. Power Derating

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# 2N3773 2N6609

## PACKAGE DIMENSIONS

### CASE 1-07 TO-204AA (TO-3) ISSUE Z



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550	REF	39.37	REF
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430	BSC	10.92	BSC
H	0.215	BSC	5.46	BSC
K	0.440	0.480	11.18	12.19
L	0.665	BSC	16.89	BSC
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187	BSC	30.15	BSC
V	0.131	0.188	3.33	4.77

#### STYLE 1:

- PIN 1. BASE
  2. Emitter
- CASE: COLLECTOR

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